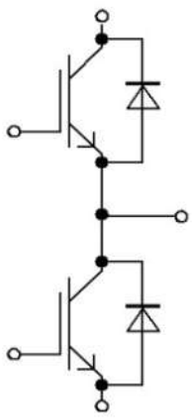
C2 series package: 1200V 300A IGBT module

Datasheet



Equivalent
Circuit Schematic

Features:

- Trenchgate Gen.7 IGBT technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High RBSOA capability
- Low static losses: $V_{CE(sat)}$ = 1,5V@25℃
- Low dynamic losses

Options:

- Pre-applied TIM (option +M01)
- Adoption for parallel connection (Vf selection)

Typical Applications:

- High Power Converters
- Motor Drives
- Uninterrupted Power Supply
- Photovoltaic

IGBT, Inverter / IGBT
Maximum Rated Values

Collector-emitter Voltage	T_{vj} = 25℃	V_{CES}	1200	V
Continuous DC Collector Current		I_{Cnom}	300	A
	T_C = 80℃, $T_{vj\ max}$ = 175℃	I_C	390	A
Repetitive Peak Collector Current	I_{CRM} = 2 x I_{cnom}	I_{CRM}	600	A
Total Power Dissipation	T_C = 25℃, $T_{vj\ max}$ = 175℃	P_{tot}	1440	W
Gate-emitter Peak Voltage		V_{GES}	±20	V

Characteristic Values

			min.	typ.	max.	
Collector-emitter Saturation Voltage[1)]	I_C = 300A, V_{GE} = 15V	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	V_{CEsat}		1.50 1.71 1.87 1.93	1.70	V
Gate Threshold Voltage	V_{CE} = V_{GE}, I_C = 12mA, T_{vj} = 25℃		V_{GEth}	5.0	6.0	7.0	V
Gate Charge	V_{GE} = -8V/15V, V_{CE} = 600V, T_{vj} = 25℃		Q_G	–	2.5	–	µC
Internal Gate Resistor	T_{vj} = 25℃		R_{Gint}	–	0.9	–	Ω
Input Capacitance	V_{CE} = 25V, V_{GE} = 0V f = 100 Khz, T_{vj} = 25℃		C_{ies}	–	71	–	nF
Reverse Transfer Capacitance			C_{res}	–	0.18	–	nF
Collector-emitter Cutoff Current	V_{CE} = 1200V, V_{GE} = 0V, T_{vj} = 25℃		I_{CES}	–	–	100	µA
Gate-emitter Leakage Current	V_{CE} = 0V, V_{GE} = ±20V, T_{vj} = 25℃		I_{GES}	–	–	±100	nA
Turn-on Delay Time, Inductive Load	I_C = 300A, V_{CE} = 600V V_{GE} = 15V/-8V R_{GON} = 1.5Ω	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	t_{don}	–	265 270 273 275	–	ns
Rise Time, Inductive Load	I_C = 300A, V_{CE} = 600V V_{GE} = 15V/-8V R_{gon} = 1.5Ω	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	t_r	–	62 72 77 82	–	ns
Turn-off Delay Time, Inductive Load	I_C = 300A, V_{CE} = 600V V_{GE} = 15V/-8V R_{goff} = 1.5Ω	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	t_{doff}	–	441 490 490 500	–	ns
Fall Time, Inductive Load	I_C = 300A, V_{CE} = 600V V_{GE} = 15V/-8V R_{Goff} = 1.5Ω	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	t_f	–	128 204 225 245	–	ns
Turn-on Energy Loss per Pulse	I_C = 300A, V_{CE} = 600V, Lσ = 45nH, V_{GE} = 15V/-8V, R_{Gon} = 1.5Ω, di/dt = 3000A/µs (T_{vj} = 175℃)	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	E_{on}	–	20.3 30.4 34.5 37.0	–	mJ
Turn-off energy Loss per Pulse	I_C = 300A, V_{CE} = 600V, Lσ = 45nH, R_{Goff} = 1.5Ω V_{GE} = 15V/-8V, dv/dt = 7000V/µs (T_{vj} = 175℃)	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	E_{off}	–	25.6 34.2 35.7 38.2	–	mJ

SC Data	V_{CE} = 600V, V_{GE} = 15V/-8V, T_{vj} = 150℃	t_{psc}	8	-	-	μs
Thermal Resistance, Junction to Case	Per IGBT / IGBT	R_{thJC}	-	0.104	-	K/W
Temperature under Switching Conditions		$T_{vj\ op}$	-40	-	150	℃

Diode, Inverter
Maximum Rated Values

Repetitive Peak Reverse Voltage	T_{vj} = 25℃	V_{RRM}	1200	V
Continuous DC Forward Current		I_F	300	A
Repetitive Peak Forward Current	I_{CRM} = 2 x I_{fnom}	I_{FRM}	600	A

Characteristic Values

				min.	typ.	max.	
Forward Voltage[1)]	I_F = 300A, V_{GE} = 0V	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	V_F		1.92 1.90 1.84 1.78	2.40	V
Peak Reverse Recovery Current	I_F = 300A, V_R = 600V -di_F/dt = 2800A/us (T_{vj} = 175℃) V_{GE} = −8V	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	I_{RM}	-	170 195 205 210	-	A
Recovery Charge	I_F = 300A, V_R = 600V -di_F/dt = 2800A/us (T_{vj} = 175℃) V_{GE} = −8V	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	Q_R	-	11.0 28.5 34.5 40.0	-	uC
Reverse Recovery Energy	I_F = 300A, V_R = 600V -di_F/dt = 2800A/us (T_{vj} = 175℃) V_{GE} = −8V	T_{vj} = 25℃ T_{vj} = 125℃ T_{vj} = 150℃ T_{vj} = 175℃	E_{rec}	-	5.8 12.5 15.0 18.0	-	mJ
Thermal Resistance, Junction to Case	Per Doide / Diode		R_{thJC}	-	0.172	-	K/W
Temperature under Switching Conditions			$T_{vj\ op}$	-40	-	150	℃

Module

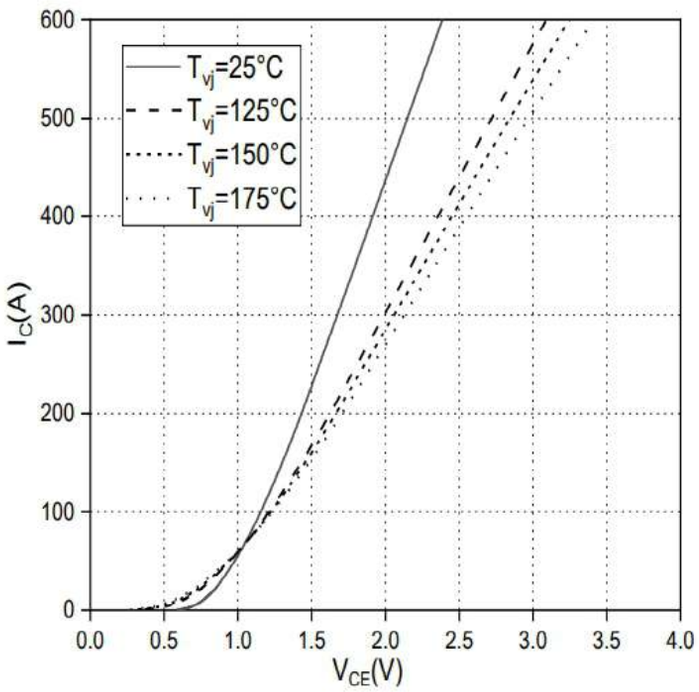
Isolation Test Voltage	RMS, f = 50Hz, t = 1min	V_{ISOL}	3.0	kV
Material of Module Baseplate			Cu	
Internal Isolation	(class 1, IEC 61140) Basic insulation (class 1, IEC 61140)		AL_2O_3	
Creepage Distance	Terminal to heatsink Terminal to terminal		29.0 23.0	mm
Clearance	Terminal to heatsink Terminal to terminal		23.0 11.0	mm
Comparative Tracking Index		CTI	＞400	

			min.	typ.	max.	
Stray Inductance Module		L_{sCE}	-	20	-	nH
Module Lead Resistance, Terminals-Chip	T_C = 25℃, Per Switch	$R_{CC'+EE'}$	-	0.70	-	mΩ
Storage Temperature		T_{stg}	-40	-	125	℃
Modul MountingTorque	M6	M	4.0	-	6.0	Nm
Terminal MountingTorque	M6	M	4.0	-	6.0	Nm
Weight		G	-	320	-	g

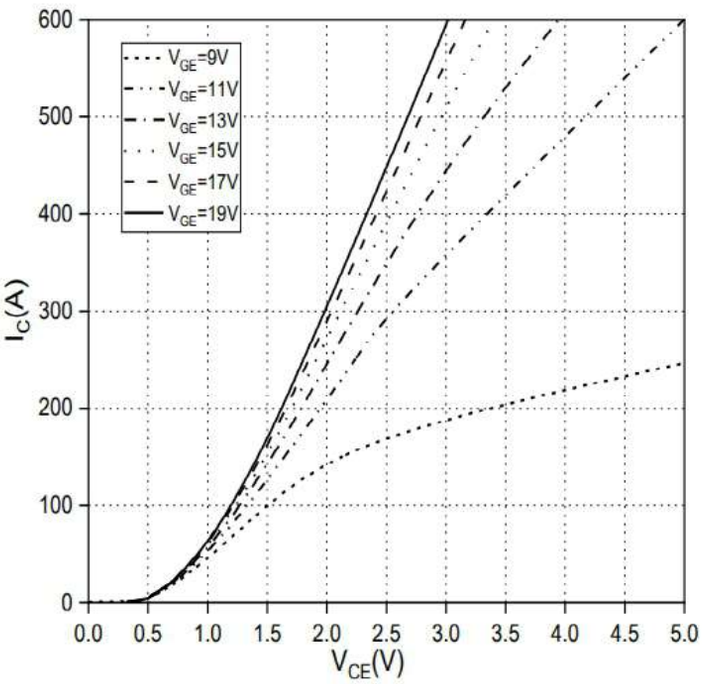
1) Terminal impedance is not included.

Circuit Diagram

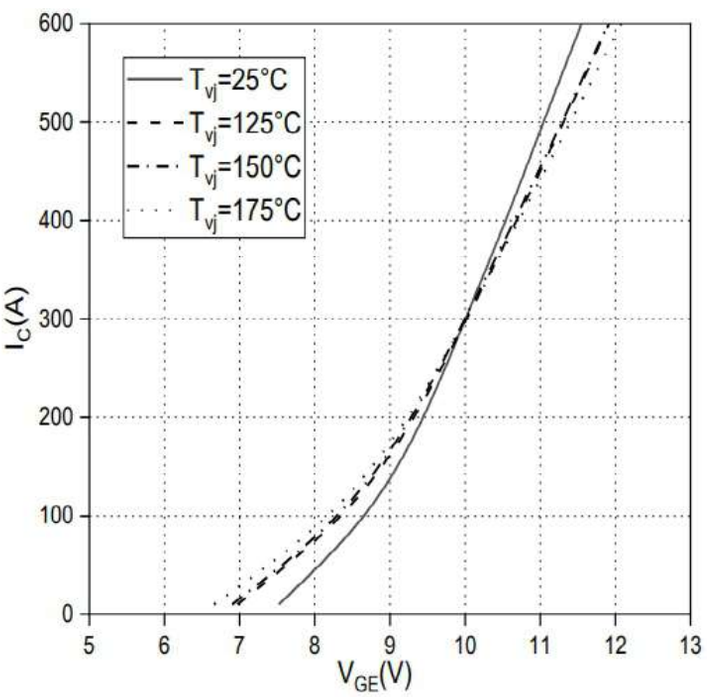
Output characteristic IGBT, Inverter (typical), IGBT
$I_C = f(V_{CE})$, V_{GE} = 15V



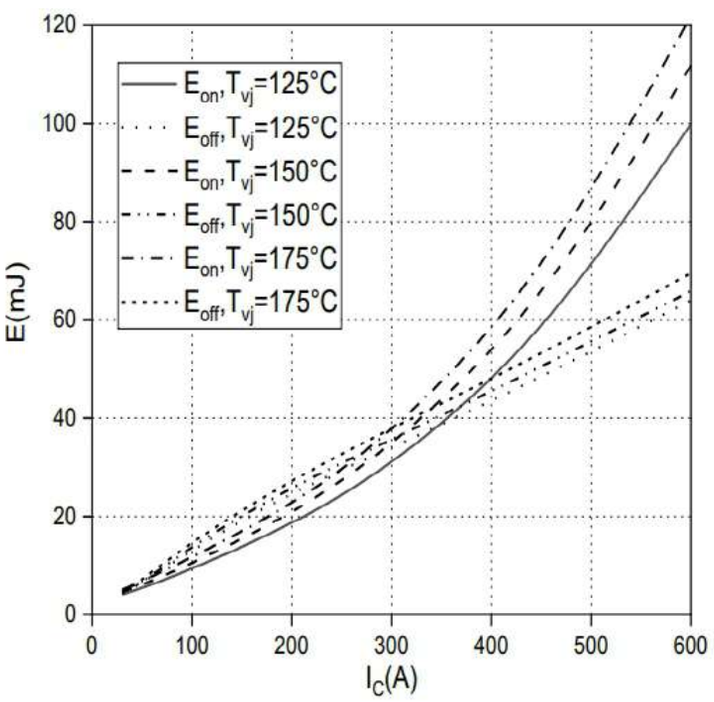
Output characteristic IGBT, Inverter (typical), IGBT
$I_C = f(V_{CE})$, T_{vj} = 175°C



Transfer characteristic IGBT,Inverter(typical), IGBT
$I_C = f(V_{GE})$, V_{CE} = 20V

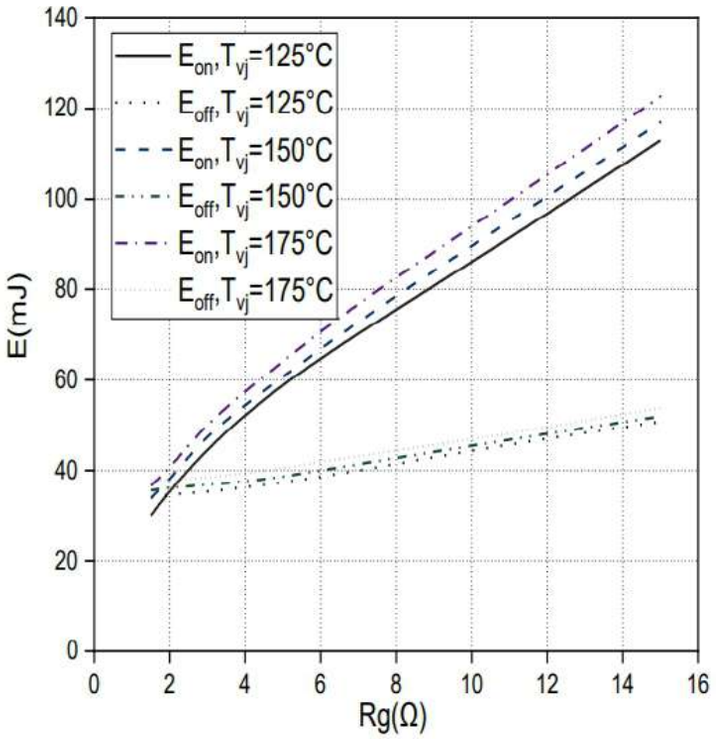


Switching losses IGBT, Inverter (Typical), IGBT
$E_{on} = f(I_C)$, $E_{off} = f(I_C)$
V_{GE} = +15V/-8V, R_{Gon} = 1.5Ω, R_{Goff} = 1.5Ω, V_{CE} = 600V



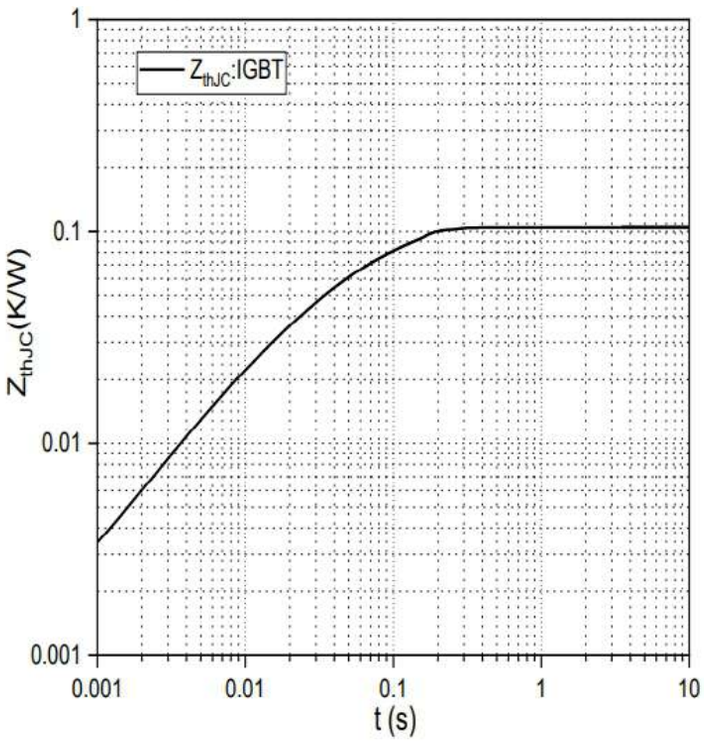
Switching losses IGBT, Inverter (typical), IGBT

V_{GE} = +15V/-8V, I_C = 300A, V_{CE} = 600V

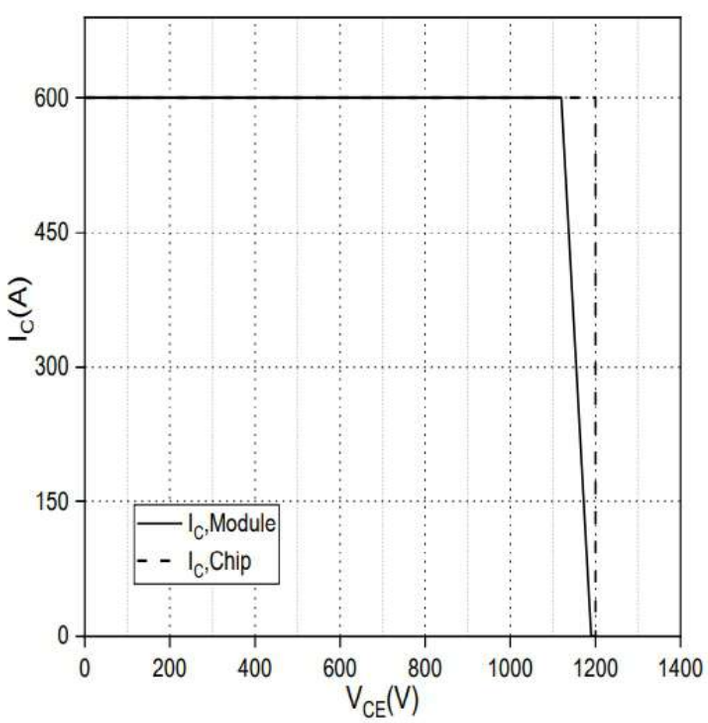


Transient thermal impedance IGBT, Inverter

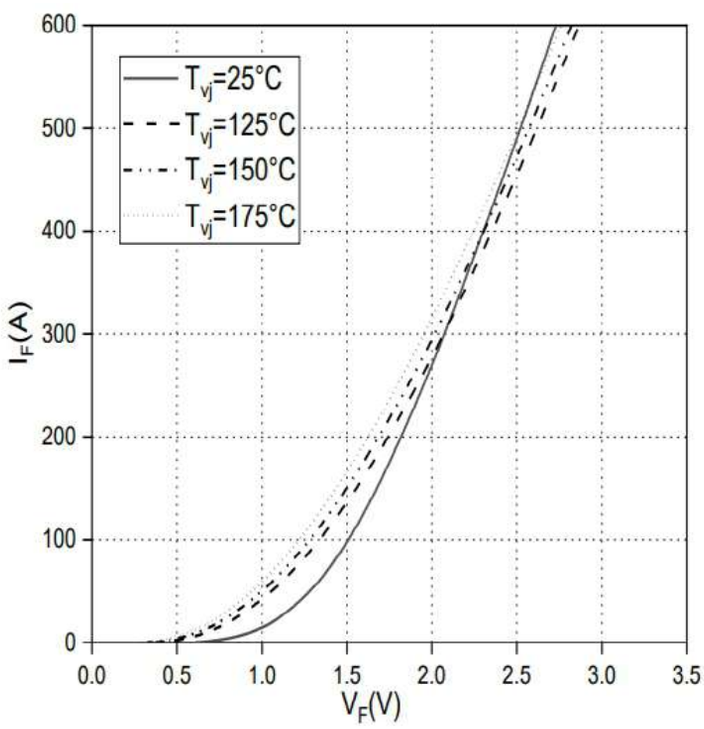
Z_{thJC} = f(t)



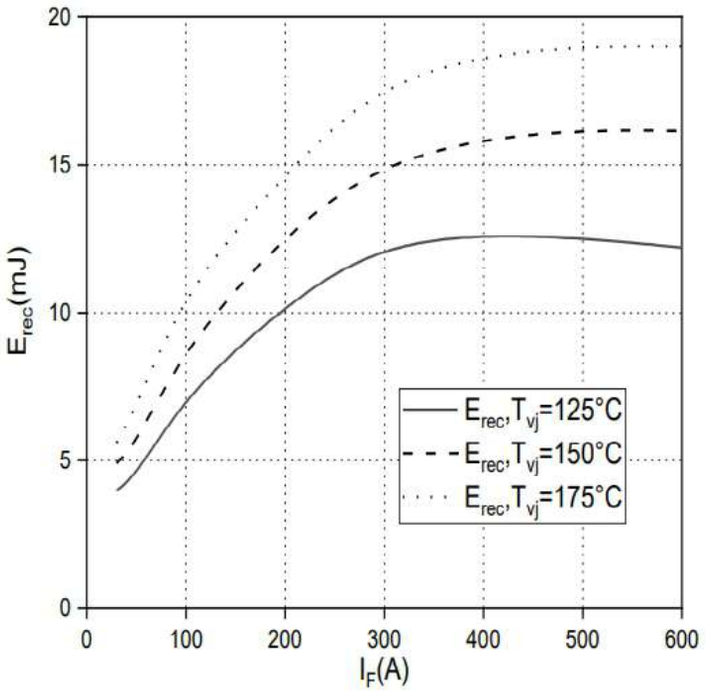
Reverse bias safe operating area IGBT, Inverter (RBSOA) I_C = f(V_{CE}),
V_{GE} = 15V/-8V, R_{Goff} = 1.5Ω,T_{vj} = 175°C



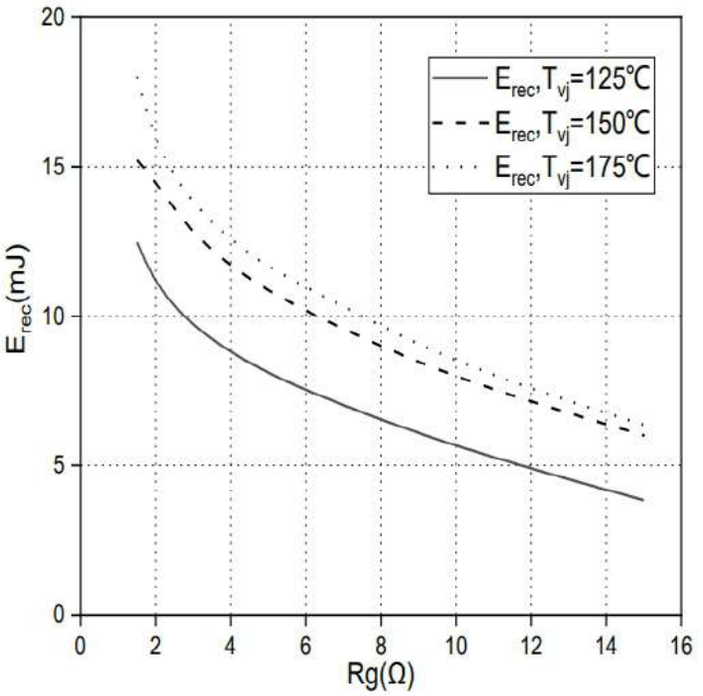
Forward characteristic of Diode, Inverter (typical)
I_F = f(V_F)



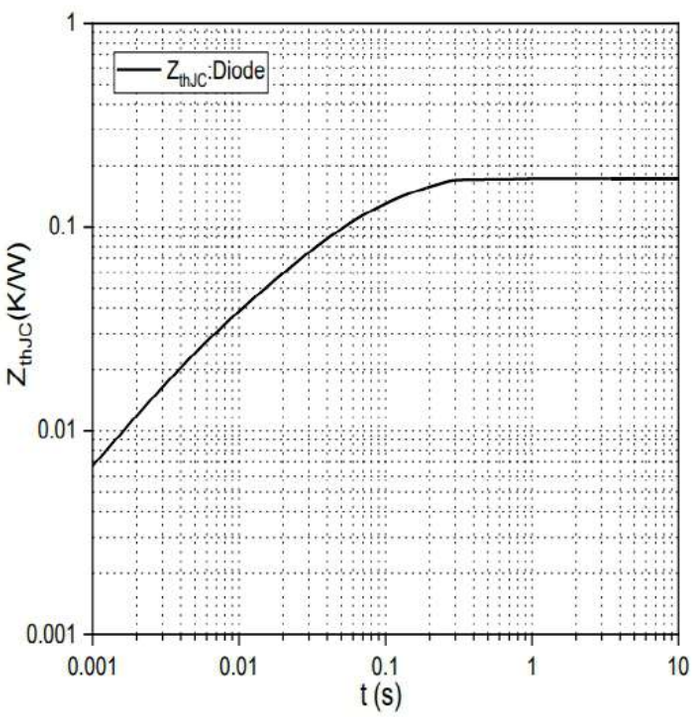
Switching losses Diode, Inverter (typical)
$E_{rec} = f(I_F)$, $R_{gon} = 1.5\Omega$, $V_{CE} = 600V$



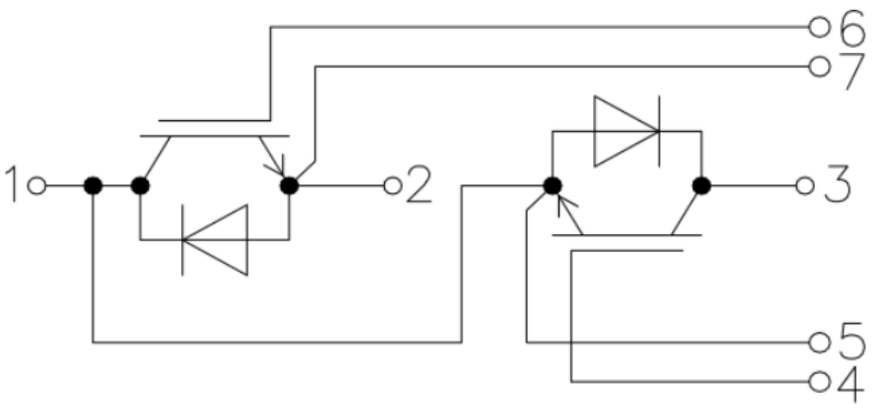
Switching losses Diode, Inverter (typical)
$E_{rec} = f(R_G)$, $I_F = 300A$, $V_{CE} = 600V$



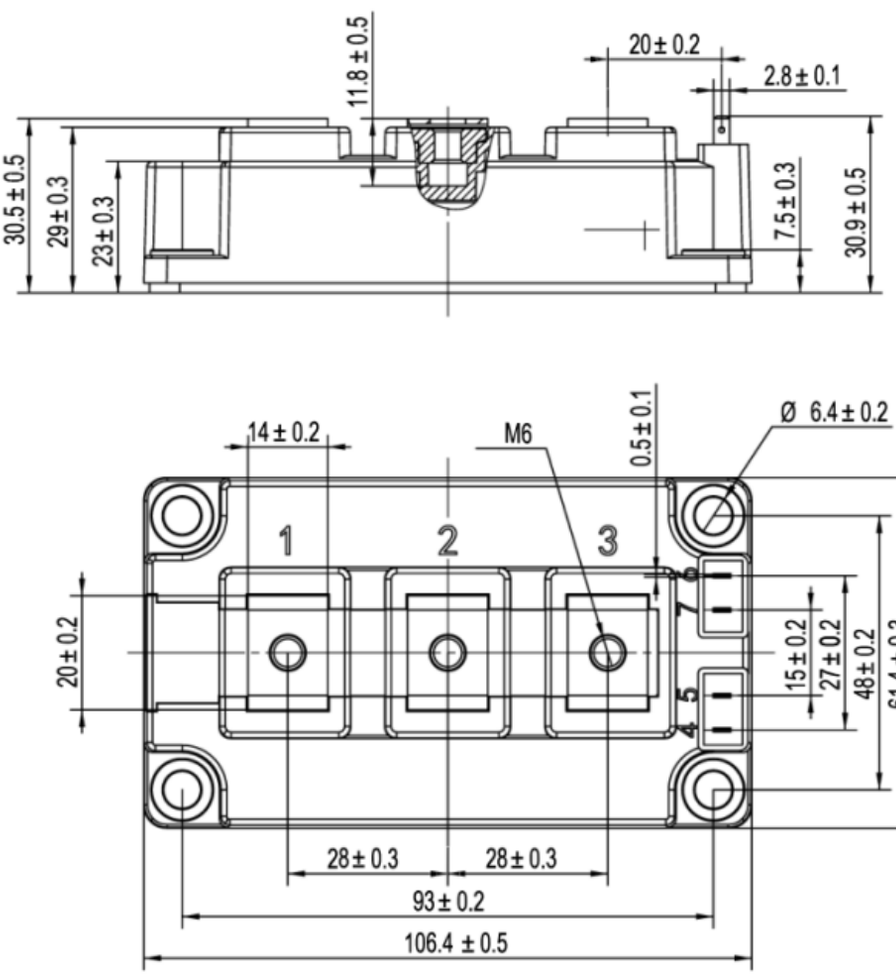
Transient thermal impedance Diode , Inverter
$Z_{thJC} = f(t)$



Internal Circuit



Package Dimension
Dimensions in Millimeters



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